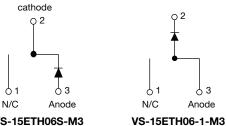
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VS-15ETH06S-M3, VS-15ETH06-1-M3

Vishay Semiconductors

Hyperfast Rectifier, 15 A FRED Pt[®]

2 3 **TO-262AA** D²PAK (TO-263AB) Base



VS-15ETH06S-M3

PRIMARY CHARACTE	RISTICS
I _{F(AV)}	15 A
V _R	600 V
V _F at I _F	1.3 V
t _{rr} (typ.)	22 ns
T _J max.	175 °C
Package	D ² PAK (TO-263AB), TO-262AA
Circuit configuration	Single

FEATURES

- · Hyperfast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- · Single die center tap module
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 140 °C	15			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	120	A		
Peak repetitive forward current	I _{FM}		30			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFIC	$T_{\rm J} = 150 ^{\circ}{\rm C}, V_{\rm R} = V_{\rm R} \text{rated}$ - 30 500					
PARAMETER	SYMBOL	$\begin{tabular}{ c c c c c c c } \hline TEST CONDITIONS & MIN. & TYP. & MAX. & UNITS \\ \hline I_R = 100 \ \mu A & 600 & - & - & \\ \hline I_F = 15 \ A & - & 1.8 & 2.2 & \\ \hline I_F = 15 \ A, \ T_J = 150 \ ^{\circ}C & - & 1.3 & 1.6 & \\ \hline V_R = V_R \ rated & - & 0.2 & 50 & \\ \hline T_J = 150 \ ^{\circ}C, \ V_R = V_R \ rated & - & 30 & 500 & \\ \hline V_R = 600 \ V & - & 20 & - & pF & \\ \hline \end{tabular}$				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
	V	I _F = 15 A	-	1.8	2.2	V
Forward voltage	۷F	I _F = 15 A, T _J = 150 °C	-	1.3	1.8 2.2 1.3 1.6 0.2 50	
Reverse leakage current	I_	$V_R = V_R$ rated	-	0.2	50	
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	30	500	μΑ
Junction capacitance	CT	V _R = 600 V	-	20	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH

RoHS COMPLIANT

HALOGEN FREE

1



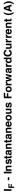
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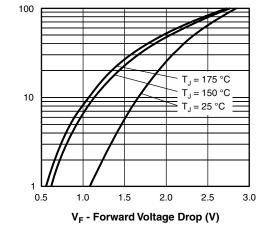
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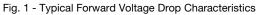
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DYNAMIC RECOVERY	CHARACT	ERISTICS (T _C = 25	5 °C unless otherwis	e specifie	ed)		
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		I _F = 1 A, dI _F /dt = 1	00 A/µs, V _R = 30 V	-	22	30	
Reverse recovery time	+	I _F = 15 A, dI _F /dt =	100 A/µs, V _R = 30 V	-	28	35	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	29	-	115
		T _J = 125 °C	I _F = 15 A dI _F /dt = 200 A/μs V _B = 390 V	-	75	-	
Deels receiver a current	1	T _J = 25 °C		-	3.5	-	- A
Peak recovery current	IRRM	T _J = 125 °C		-	7	-	A
		T _J = 25 °C		-	57	-	ns Α μC ns Α
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	300	-	μΟ
Reverse recovery time	t _{rr}		I _F = 15 A	-	51	-	ns
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 800 A/µs	-	20	-	А
Reverse recovery charge	Q _{rr}		V _R = 390 V	-	580	-	nC

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance, junction to case per leg	R _{thJC}		-	1.0	1.3			
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	20 °C/W		
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-			
W/oight			-	2.0	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking daying		Case style D ² PAK (TO-263AB)		15ET	H06S			
Marking device		Case style TO-262AA		15ET	H06-1			







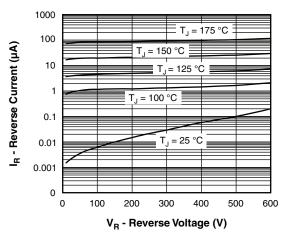


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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2

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VS-15ETH06S-M3, VS-15ETH06-1-M3

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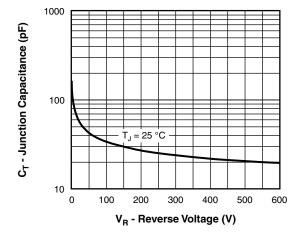


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

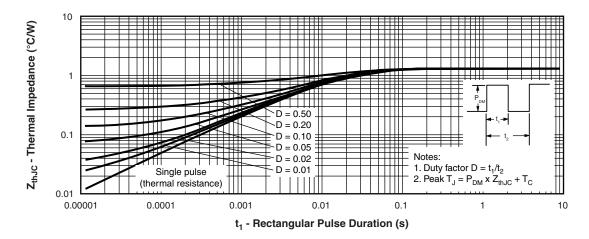
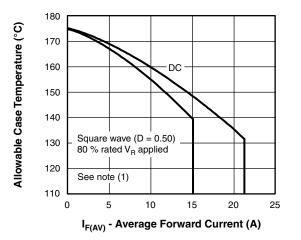
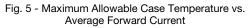


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

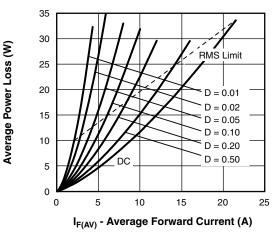


Fig. 6 - Forward Power Loss Characteristics

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3

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VS-15ETH06S-M3, VS-15ETH06-1-M3



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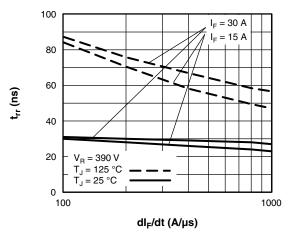


Fig. 7 - Typical Reverse Recovery vs. dl_F/dt

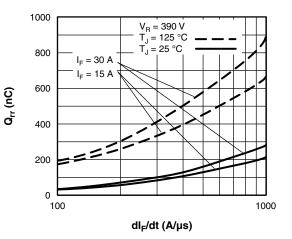


Fig. 8 - Typical Stored Charge vs. dl_F/dt

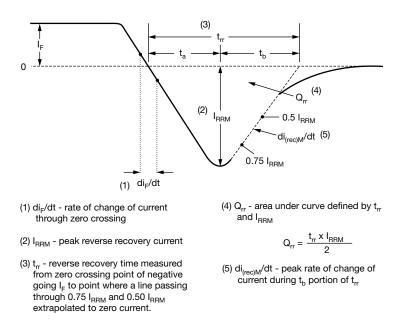


Fig. 9 - Reverse Recovery Waveform and Definitions



Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com

SHAY

Device code	vs-	15	Е	т	н	06	S	TRL	-M3
		(2)	(3)	4	(5)	6	(7)	(8)	(9)
	1 - 2 -		-	niconduo ng (15 A		oduct			
	3 -	E =	single o	liode					
	4 - 5 -			, D ² PAł ist rectifi		63AB)			
	6 -		• •	ng (06 =)			
	7 -		= D ² PA = TO-2	K (TO-2	63AB)				
	8 -			62ΑΑ be (50 μ	oieces)				
			-		-			PAK (T	
						nt orient	ed, for l	D ² PAK ((TO-263
	9 -	- Env	ironmer	ntal digit:					

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-15ETH06S-M3	50	Antistatic plastic tubes				
VS-15ETH06STRR-M3	800	13" diameter plastic tape and reel				
VS-15ETH06STRL-M3	800	13" diameter plastic tape and reel				
VS-15ETH06-1-M3	50	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS							
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164					
Dimensions	TO-262	www.vishay.com/doc?96165					
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444					
Fart marking information	TO-262	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?96424					
SPICE model		www.vishay.com/doc?96617					

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN. MAX.		NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INCHES		NOTES	
	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
	D1	6.86	8.00	0.270	0.315	3
	E	9.65	10.67	0.380	0.420	2, 3
	E1	7.90	8.80	0.311	0.346	3
	е	2.54	2.54 BSC		0.100 BSC	
	Н	14.61	15.88	0.575	0.625	
	L	1.78	2.79	0.070	0.110	
	L1	-	1.65	-	0.066	3
	L2	1.27	1.78	0.050	0.070	
	L3	0.25	BSC	0.010	BSC	
	L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 13-Jul-17

1

Document Number: 96164

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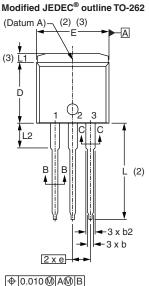
Outline Dimensions

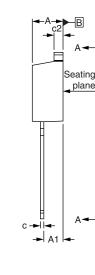


Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

CVMPOI	MILLIN	IETERS	INC	HES	10770
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis and the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

1



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